# MCH3476

# N-Channel Power MOSFET 20V, 2A, 125mΩ, Single MCPH3



http://onsemi.com

#### **Features**

- 1.8V drive
- · Halogen free compliance
- · Protection diode in

## **Specifications**

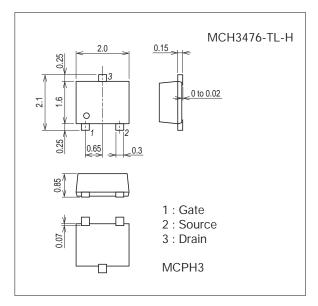
#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±12	V
Drain Current (DC)	ID		2	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	8	А
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm <sup>2</sup> ×0.8mm)	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### **Package Dimensions**

unit : mm (typ) 7019A-003

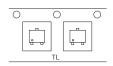


### **Product & Package Information**

• Package : MCPH3

• JEITA, JEDEC : SC-70, SOT-323 • Minimum Packing Quantity : 3,000 pcs./reel

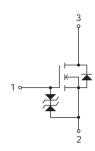
#### Packing Type: TL



## Marking



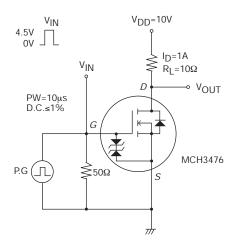
#### **Electrical Connection**



#### Electrical Characteristics at Ta=25°C

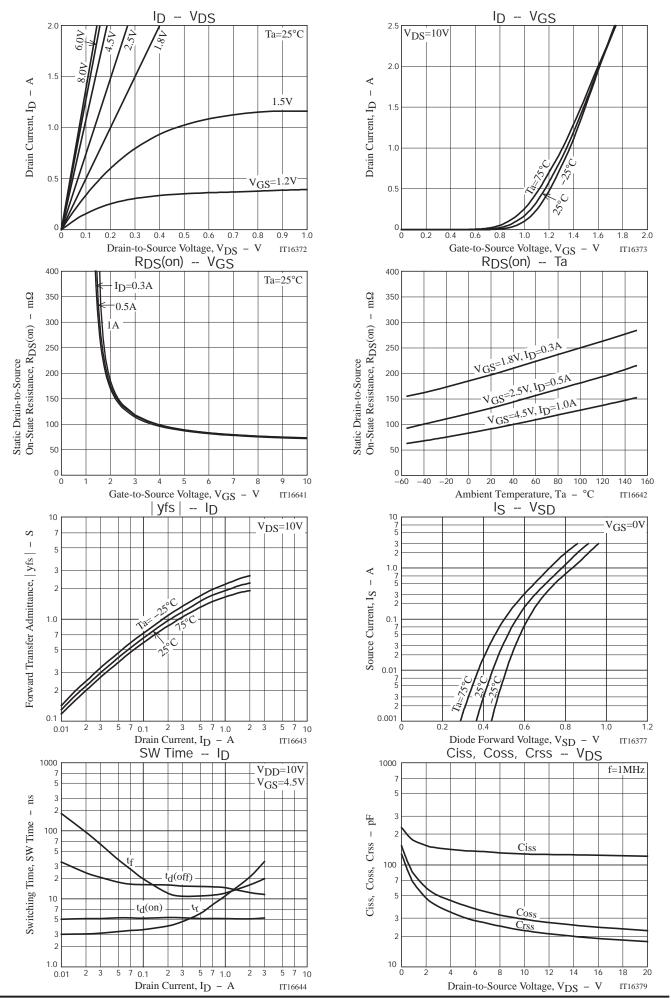
Parameter	Cumbal	Conditions	Ratings			Unit	
Parameter	Symbol	Conditions	min	typ	max	Unit	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V	
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V			1	μΑ	
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0V			±10	μΑ	
Cutoff Voltage	V <sub>GS</sub> (off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	0.4		1.3	V	
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =1A		1.9		S	
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =1A, V <sub>G</sub> S=4.5V	I <sub>D</sub> =1A, V <sub>GS</sub> =4.5V		125	mΩ	
	R <sub>DS</sub> (on)2	I <sub>D</sub> =0.5A, V <sub>GS</sub> =2.5V		135	190	mΩ	
	R <sub>DS</sub> (on)3	I <sub>D</sub> =0.3A, V <sub>GS</sub> =1.8V		200	310	mΩ	
Input Capacitance	Ciss			128		pF	
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		28		pF	
Reverse Transfer Capacitance	Crss			21		pF	
Turn-ON Delay Time	t <sub>d</sub> (on)			5.1		ns	
Rise Time	t <sub>r</sub>	Can appointed Toot Circuit		11		ns	
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		14.5		ns	
Fall Time	tf			12		ns	
Total Gate Charge	Qg			1.8		nC	
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =10V, V <sub>GS</sub> =4.5V, I <sub>D</sub> =2A		0.3		nC	
Gate-to-Drain "Miller" Charge	Qgd			0.55		nC	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =2A, V <sub>GS</sub> =0V		0.85	1.2	V	

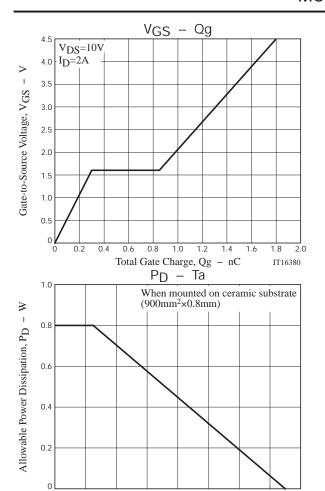
# Switching Time Test Circuit



## **Ordering Information**

Device	Package	Shipping	memo
MCH3476-TL-H	MCPH3	3,000pcs./reel	Pb Free and Halogen Free





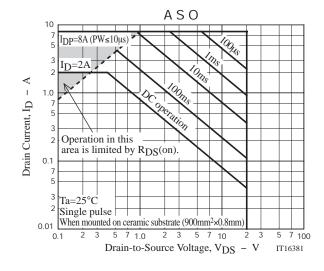
40 60 80 100 120 Ambient Temperature, Ta – °C

140

0 160 IT16382

20

0

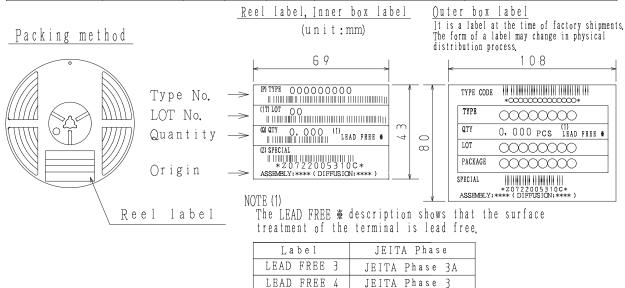


# Taping Specification

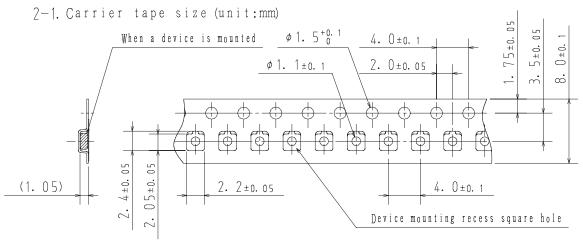
#### MCH3476-TL-H

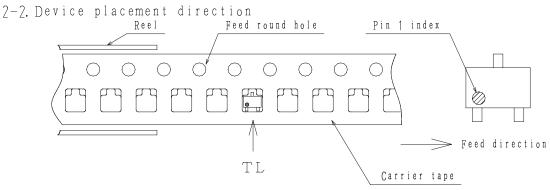
#### 1. Packing Format

Package Name	Carrier Tape	Maximun Number of devices contained (pcs)			Packing	g format		
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)		
мсрн3	мсрн3	3, 000	15, 000	90,000	5 reels contained	6 inner boxes contained		
					Dimensions:mm (external)	Dimensions:mm (external)		
					183×72×185	440×195×210		



## 2. Taping configuration

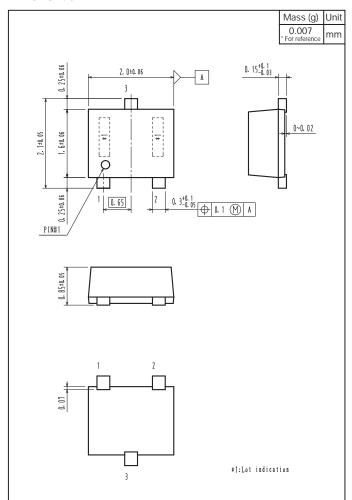




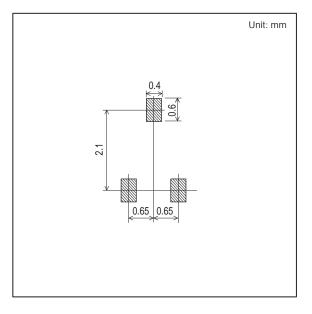
Those with pin 1 index on the feed hole side·····TL

# **Outline Drawing**

# MCH3476-TL-H



# Land Pattern Example



Note on usage: Since the MCH3476 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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